NSR30CM3T5G

Preferred Device

Dual Series Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand-held and portable applications where space is limited.

- Extremely Fast Switching Speed
- Low Forward Voltage 0.35 V (Typ) @ $I_F = 10 \text{ mA}$
- This is a Pb–Free Device

Rating	Symbol	Value	Unit		
Reverse Voltage	V _R	30	Volts		
Forward Power Dissipation @ T _A = 25°C Derate above 25°C	P _F	240 1.9	mW mW/°C		
Forward Current (DC)	١ _F	200 Max	mA		
Junction Temperature	TJ	125 Max	°C		
Storage Temperature Range	T _{stg}	-55 to +150	°C		
Thermal Resistance Junction-to-Ambient (Note 1)	R_{\thetaJA}	525	°C/W		

MAXIMUM RATINGS (T_J = 125°C unless otherwise noted)

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

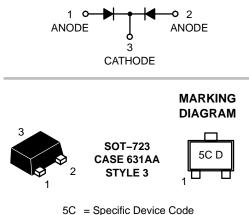
1. FR-5 board with minimum mounting pad.



ON Semiconductor®

http://onsemi.com

30 V DUAL COMMON CATHODE SCHOTTKY BARRIER DIODES



5C = Specific Device Coc D = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
NSR30CM3T5G	SOT–723 (Pb–Free)	8000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

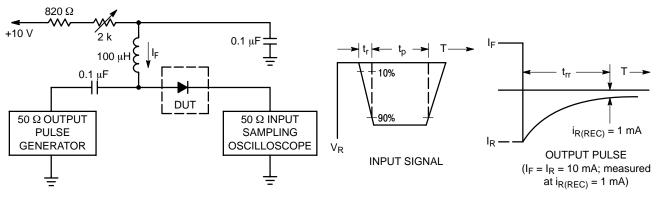
Preferred devices are recommended choices for future use and best overall value.

NSR30CM3T5G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (EACH DIODE)

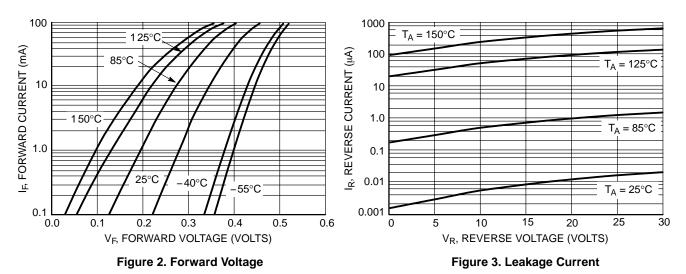
Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage ($I_R = 10 \ \mu A$)	V _{(BR)R}	30	-	-	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	CT	-	7.6	10	pF
Reverse Leakage ($V_R = 25 V$)	I _R	_	0.5	2.0	μΑ
Forward Voltage (I _F = 0.1 mA)	V _F	-	0.22	0.24	V
Forward Voltage (I _F = 30 mA)	V _F	-	0.41	0.5	V
Forward Voltage (I _F = 100 mA)	V _F	-	0.52	0.8	V
Reverse Recovery Time $(I_F = I_R = 10 \text{ mA}, I_{R(REC)} = 1.0 \text{ mA}, Figure 1)$	t _{rr}	-	-	5.0	ns
Forward Voltage (I _F = 1.0 mA)	V _F	-	0.29	0.32	V
Forward Voltage (I _F = 10 mA)	V _F	-	0.35	0.40	V
Forward Current (DC)	۱ _F	-	-	200	mA
Repetitive Peak Forward Current	I _{FRM}	-	-	300	mA
Non-Repetitive Peak Forward Current (t < 1.0 s)	I _{FSM}	_	-	600	mA

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Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA. 2. Input pulse is adjusted so I_{R(peak)} is equal to 10 mA. 3. t_p » t_{rr}





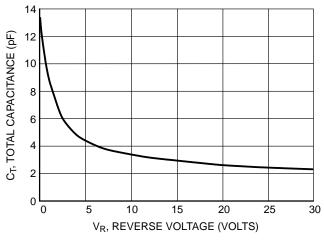
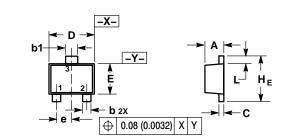


Figure 4. Total Capacitance

PACKAGE DIMENSIONS

SOT-723 CASE 631AA-01 ISSUE B



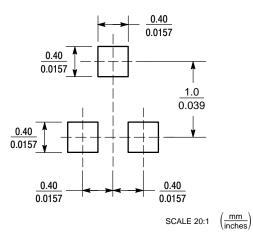
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM 3. THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- 4 FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.45	0.50	0.55	0.018	0.020	0.022	
b	0.15	0.21	0.27	0.0059	0.0083	0.0106	
b1	0.25	0.31	0.37	0.010	0.012	0.015	
С	0.07	0.12	0.17	0.0028	0.0047	0.0067	
D	1.15	1.20	1.25	0.045	0.047	0.049	
Е	0.75	0.80	0.85	0.03	0.032	0.034	
е	0.40 BSC			0	0.016 BSC		
ΗE	1.15	1.20	1.25	0.045	0.047	0.049	
L	0.15	0.20	0.25	0.0059	0.0079	0.0098	

STYLE 3: PIN 1. ANODE

2. ANODE 3. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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